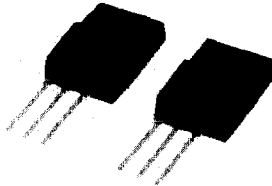


FS16KM-5

HIGH-SPEED SWITCHING USE

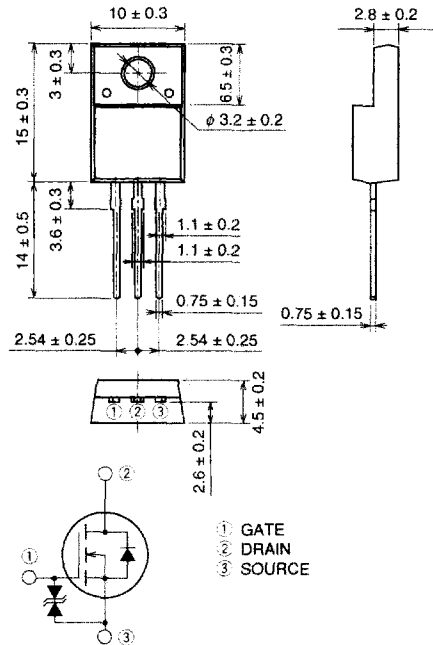
FS16KM-5



- V_{DSS} 250V
- $r_{DS(ON)}$ (MAX) 0.25 Ω
- I_D 16A
- V_{iso} 2000V

OUTLINE DRAWING

Dimensions in mm



TO-220FN

APPLICATION

SMPS, DC-DC Converter, battery charger, power supply of printer, copier, HDD, FDD, TV, VCR, personal computer etc.

MAXIMUM RATINGS (Tc = 25°C)

Symbol	Parameter	Conditions	Ratings	Unit
V_{DSS}	Drain-source voltage	$V_{GS} = 0V$	250	V
V_{GSS}	Gate-source voltage	$V_{DS} = 0V$	± 30	V
I_D	Drain current		16	A
I_{DM}	Drain current (Pulsed)		48	A
P_D	Maximum power dissipation		35	W
T_{ch}	Channel temperature		-55 ~ +150	°C
T_{stg}	Storage temperature		-55 ~ +150	°C
V_{iso}	Isolation voltage	AC for 1minute, Terminal to case	2000	Vrms
—	Weight	Typical value	2.0	g

FS16KM-5

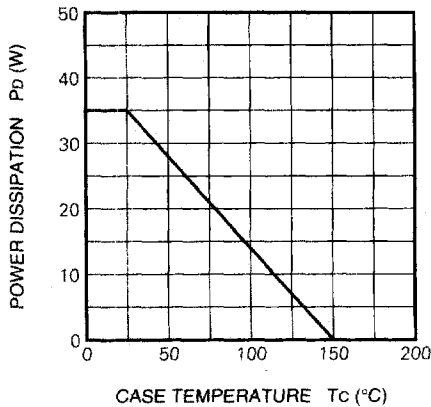
HIGH-SPEED SWITCHING USE

ELECTRICAL CHARACTERISTICS (Tch = 25°C)

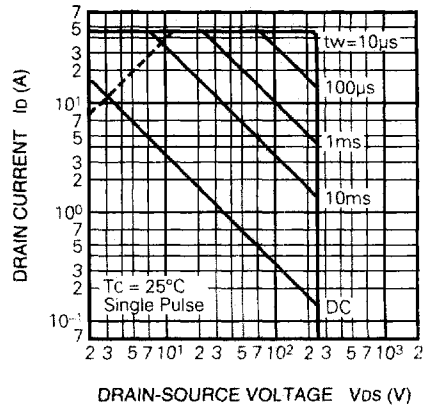
Symbol	Parameter	Test conditions	Limits			Unit
			Min.	Typ.	Max.	
V(BR)DSS	Drain-source breakdown voltage	Id = 1mA, VGS = 0V	250	—	—	V
V(BR)GSS	Gate-source breakdown voltage	IG = ±100μA, VDS = 0V	±30	—	—	V
IGSS	Gate leakage current	VGS = ±25V, VDS = 0V	—	—	±10	μA
IDSS	Drain current	VDS = 250V, VGS = 0V	—	—	1	mA
VGS(th)	Gate-source threshold voltage	Id = 1mA, VDS = 10V	2	3	4	V
rDS(ON)	Drain-source on-state resistance	Id = 8A, VGS = 10V	—	0.19	0.25	Ω
VDS(ON)	Drain-source on-state voltage	Id = 8A, VGS = 10V	—	1.5	2.0	V
yfs	Forward transfer admittance	Id = 8A, VDS = 10V	6.5	10.0	—	S
Ciss	Input capacitance	VDS = 25V, VGS = 0V, f = 1MHz	—	1050	—	pF
Coss	Output capacitance		—	220	—	pF
Crss	Reverse transfer capacitance		—	45	—	pF
td(on)	Turn-on delay time		—	20	—	ns
tr	Rise time	VDD = 150V, Id = 8A, VGS = 10V, RGEN = RGS = 50Ω	—	40	—	ns
td(off)	Turn-off delay time		—	110	—	ns
tf	Fall time		—	50	—	ns
VSD	Source-drain voltage	IS = 8A, VGS = 0V	—	1.5	2.0	V
Rth(ch-c)	Thermal resistance	Channel to case	—	—	3.57	°C/W

PERFORMANCE CURVES

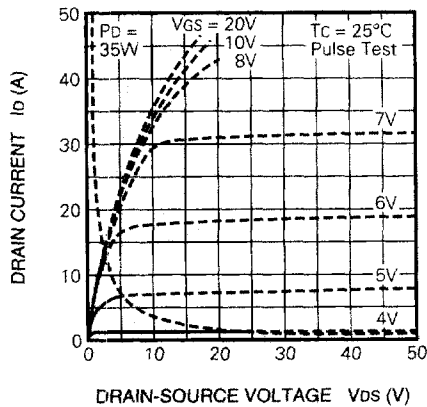
POWER DISSIPATION DERATING CURVE



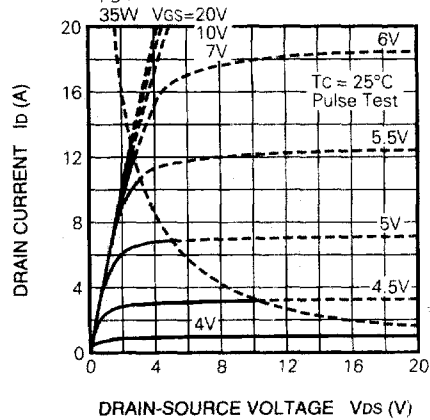
MAXIMUM SAFE OPERATING AREA



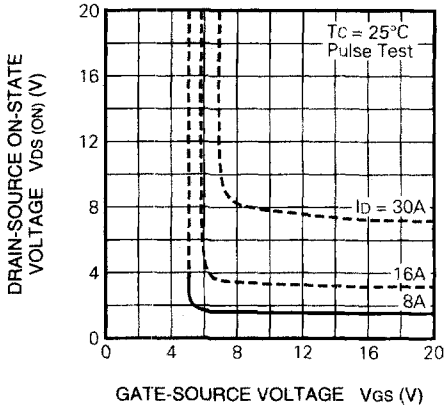
OUTPUT CHARACTERISTICS (TYPICAL)



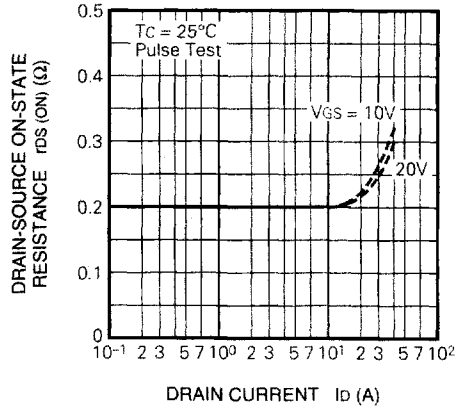
OUTPUT CHARACTERISTICS (TYPICAL)



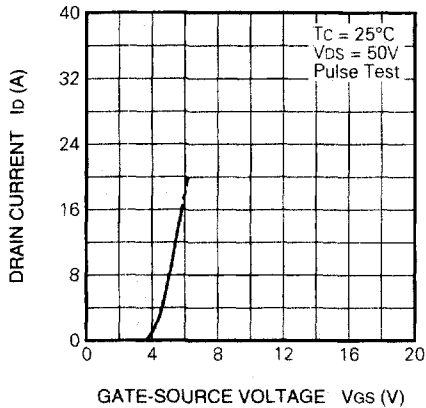
ON-STATE VOLTAGE VS. GATE-SOURCE VOLTAGE (TYPICAL)



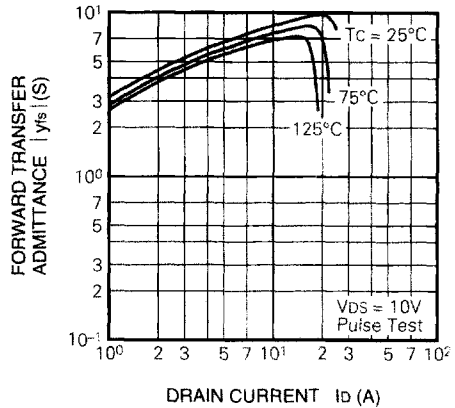
ON-STATE RESISTANCE VS. DRAIN CURRENT (TYPICAL)



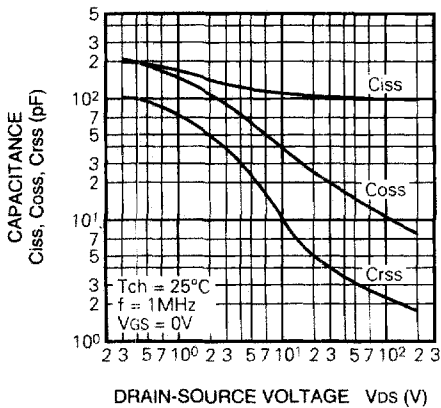
TRANSFER CHARACTERISTICS (TYPICAL)



FORWARD TRANSFER ADMITTANCE VS. DRAIN CURRENT (TYPICAL)



CAPACITANCE VS. DRAIN-SOURCE VOLTAGE (TYPICAL)



SWITCHING CHARACTERISTICS (TYPICAL)

